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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Applicant: Kaiping Liu

Docket Number: TI-34717.1

Serial No.: **10/785,623**

Art Unit: 2891

Filed: 02/24/04

Examiner: Chandra P. Chaudhari

For: Method to Produce Localized Halo for MOS Transistor

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below:

Karen Vertz
Karen Vertz

3-8-06
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FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> FACSIMILE COVER SHEET	<input checked="" type="checkbox"/> AMENDMENT <u>116 (12 pages)</u>
<input type="checkbox"/> NEW APPLICATION	<input type="checkbox"/> EOT
<input type="checkbox"/> DECLARATION	<input type="checkbox"/> NOTICE OF APPEAL
<input type="checkbox"/> ASSIGNMENT	<input type="checkbox"/> APPEAL <u>(# Pages)</u>
<input type="checkbox"/> FORMAL DRAWINGS	<input type="checkbox"/> ISSUE FEE & PUBLICATION FEE (1 Page)
<input type="checkbox"/> INFORMAL DRAWINGS	<input type="checkbox"/> REPLY BRIEF (IN TRIPLICATE) (# Pages)
<input type="checkbox"/> CONTINUATION APP'N	
<input type="checkbox"/> DIVISIONAL APP'N	
NAME OF INVENTOR(S): Kaiping Liu	
TITLE OF INVENTION: Method to Produce Localized Halo for MOS Transistor	
TI FILE NO.: TI-34717.1	DEPOSIT ACCT. NO.: 20-0668
FAXED: 3-8-06 DUE: 2-16-06 ATTY/SECY: RAK/kjv	
RECEIPT DATE & SERIAL NO.: Serial No.: 10/785,623 Filing Date: 02/24/04	

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Kaiping Liu

Docket No.: TI-34717.1

Serial No.: 10/785,623

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Filed: 02/24/2004

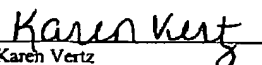
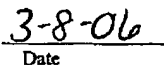
Examiner: Chaudhari, C.

Title: Method to Produce Localized Halo for MOS Transistor

AMENDMENT UNDER 37 CFR §1.116

March 8, 2006

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

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 Karen Vertz	 Date

Dear Commissioner:

In response to the Office Action, dated 12/16/2005, in the above-identified patent application, please make the following amendments. They are respectfully submitted as a full and complete response to that Action. Charge any required fees to the deposit account of Texas Instruments Incorporated, Account No. 20-0668.